# VS-SC40FA65



Vishay Semiconductors

# SOT-227 Silicon Carbide Schottky Barrier Diode, 650 V, 40 A



PRIMARY CHARACTERISTICS							
V <sub>R</sub>	650 V						
V <sub>F</sub> (typical) at 20 A, per diode	1.36 V						
Q <sub>C</sub> (typical), per diode	56 nC						
$I_{F(DC)}$ per module at $T_C = 136 \ ^{\circ}C$	40 A						
Туре	Modules - diode, SiC Schottky						
Package	SOT-227						
Circuit configuration	Two separate diodes, parallel pin-out						

### FEATURES

Virtually no recovery tail and no switching losses



COMPLIANT

- Majority carrier diode using Schottky technology on SiC wide band gap material
- Improved  $V_{\rm F}$  and efficiency by thin wafer technology
- High speed switching, low switching losses
- Positive temperature coefficient, for easy paralleling
- Electrically isolated base plate
- Large creepage distance between terminal
- · Simplified mechanical designs, rapid assembly
- · Designed and qualified for industrial level
- UL approved file E78996
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### **DESCRIPTION / APPLICATIONS**

Wide band gap SiC based 650 V Schottky diode, designed for high performance and ruggedness.

Optimum choice for high speed hard switching and efficient operation over a wide temperature range, it is also recommended for all applications suffering from Silicon ultrafast recovery behavior.

Typical applications include AC/DC PFC and DC/DC ultra high frequency output rectification in FBPS and LLC converters

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS		
Cathode to anode voltage	V <sub>R</sub>		650	V		
Continuous forward current per diode	I <sub>F</sub>	T <sub>C</sub> = 136 °C	20	^		
Single pulse forward current per diode	I <sub>FSM</sub>	T <sub>J</sub> = 25 °C, 6 ms square pulse	105	A		
Maximum power dissipation per module	PD	T <sub>C</sub> = 136 °C	74	W		
RMS isolation voltage	V <sub>ISOL</sub>	Any terminal to case, t = 1 min	2500	V		
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C		

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V <sub>BR</sub>	I <sub>R</sub> = 100 μA	650	-	-	
Forward voltage	V <sub>FM</sub>	I <sub>F</sub> = 20 A	-	1.36	1.55	V
		I <sub>F</sub> = 20 A, T <sub>J</sub> = 150 °C	-	1.57	-	
		V <sub>R</sub> = 650 V	-	1	40	
Reverse leakage current	I <sub>RM</sub>	T <sub>J</sub> = 125 °C, V <sub>R</sub> = 650 V	-	3.1	-	μA
		T <sub>J</sub> = 150 °C, V <sub>R</sub> = 650 V	-	4.6	-	
Junction capacitance	CT	V <sub>R</sub> = 650 V, f = 1 MHz	-	82	-	pF

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Total capacitive charge	Q <sub>C</sub>	V <sub>R</sub> = 400 V	-	56	-	nC

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance junction to case, per diode	P		-	-	1.06	
Thermal resistance junction to case, per module	R <sub>thJC</sub>		-	-	0.53	°C/W
Thermal resistance case to heatsink, per module	R <sub>thCS</sub>	Flat, greased surface	-	0.05	-	
Weight			-	30	-	g
Mounting torque		Torque per diode	-	-	1.1 (9.7)	Nm (lbf.in)
		Torque to heatsink	-	-	1.8 (15.9)	Nm (lbf.in)
Case style				SOT	-227	

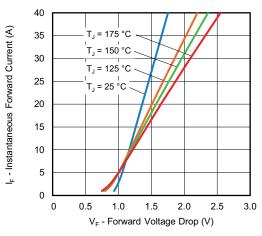


Fig. 1 - Typical Forward Voltage Drop Characteristics

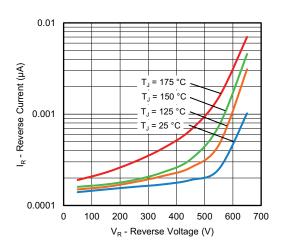


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

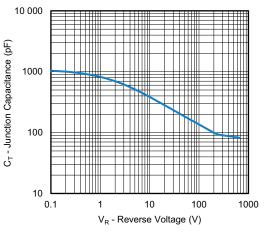


Fig. 3 - Junction Capacitance vs. Reverse Voltage

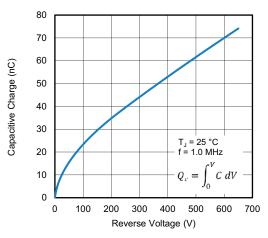


Fig. 4 - Typical Capacitive Charge vs. Reverse Voltage

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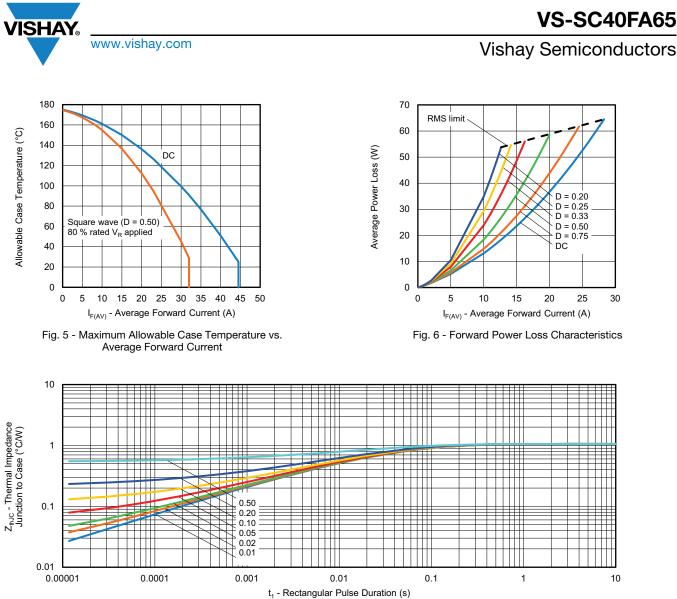
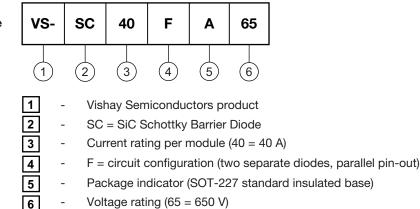


Fig. 7 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

#### **ORDERING INFORMATION TABLE**

**Device code** 



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CIRCUIT CONFI	CIRCUIT CONFIGURATION					
CIRCUIT	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING				
Two separate diodes, parallel pin-out	F	Lead Assignment				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95423				
Packaging information	www.vishay.com/doc?95425				

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SOT-227 Generation 2

#### **DIMENSIONS** in millimeters (inches)



#### Note

• Controlling dimension: millimeter



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